



IEMN - Deposition Techniques in Clean Room

Isabelle Roch-Jeune, Marc Dewitte, Carlos Moncasi, Chiara Crivello, David Guérin, Guillaume Cochez, Jérémie Chaillou

► To cite this version:

Isabelle Roch-Jeune, Marc Dewitte, Carlos Moncasi, Chiara Crivello, David Guérin, et al.. IEMN - Deposition Techniques in Clean Room. Renatech dépôts 2023, Oct 2023, Dijon, France. hal-04526167

HAL Id: hal-04526167

<https://hal.science/hal-04526167>

Submitted on 29 Mar 2024

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

IEMN - Deposition Techniques in Clean Room

Team: Isabelle Roch-Jeune, Marc Dewitte, Carlos Moncasi-Luque, Chiara Crivello, David Guerin, Guillaume Cochez, Jérémie Chaillou

SPUTTERING SYSTEMS

ALLIANCE CONCEPT DP 650n°34

- 6 DC and RF cathodes 4"
- DC pulse and RF generators
- Au, Ni, Pt, WTi, Ta, NiCr, NiCu, Al, Mo, Cu, TaN, Si, SiO₂, ...



1 LEYBOLD Z550

- 1 cathode 6" and 4 cathodes 4" RF and DC
- Magnetic layer deposition
- TbFe₂, TbCo₂, TbFeCo, FeCo, Fe, Co, CoPt, FePt, Ta, Cr



VN Sputtering 550 °C

1 ALLIANCE CONCEPT CT 200 CLUSTER

- 3 chambers , 14 targets (2" confocal, 4" planar), fully automated
- Different RF and DC pulse generators
- Single or multi-layers processes, reactive sputtering, co-sputtering, substrate bias.
- Realization of complex structures without vacuum break and cross-contamination of chambers

Ch. 1 & 2 → Metals & Nitrides (Fe, Co, Pt, VN, ...)

Ch. 3 → Metals, Nitrides & Oxides (W, WN, TiN, Ta₂O₅, ZnO, ITO, ...)



1 ELETTRORAVA NEW!

- 12 targets 4" confocal, fully automated, RF, DC, HiPIMS, bias.
- Single or multi-layers processes, reactive sputtering , co-(tri-)sputtering, substrate holder with planetary rotation



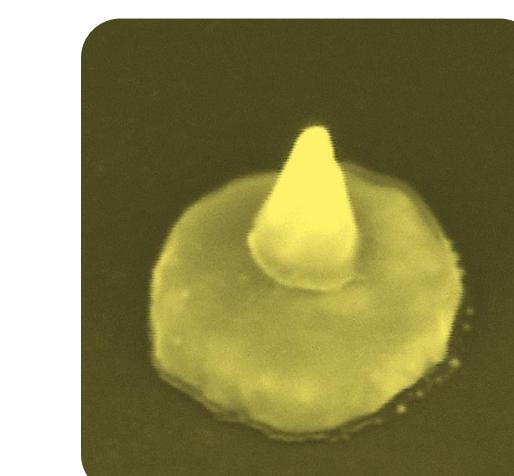
ELECTRON BEAM

1 PLASSYS MEB 450S

- Load lock
- Substrate holder 4"
- 3 sources: In, Cr, Au
- Substrate holder with planetary rotation

1 PLASSYS MEB 550SL

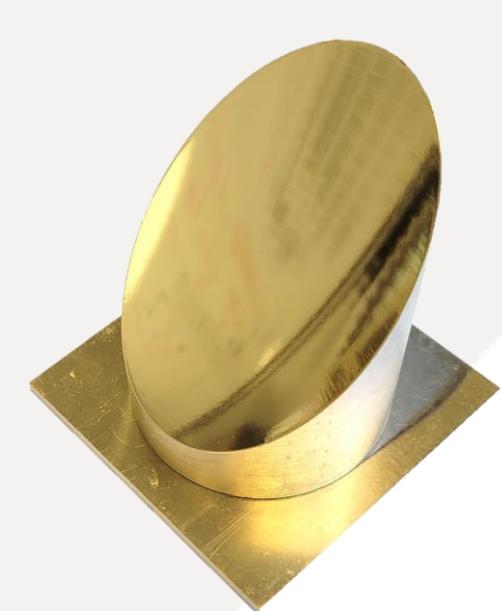
- Load lock with O₂ treatment
- Ion beam in chamber
- Substrate holder 6"
- Ti, Ni, Cr, Al, Au, Pt, Pd, Ge



Cr/Au Nanoprobe

2 PLASSYS MEB 550S

- Load lock with ion beam source
- Capacity : 4 substrate holders 4"
- Au, Ti, Ge, Al, Pt, Ni, Mo, Cr, Pd, Ag



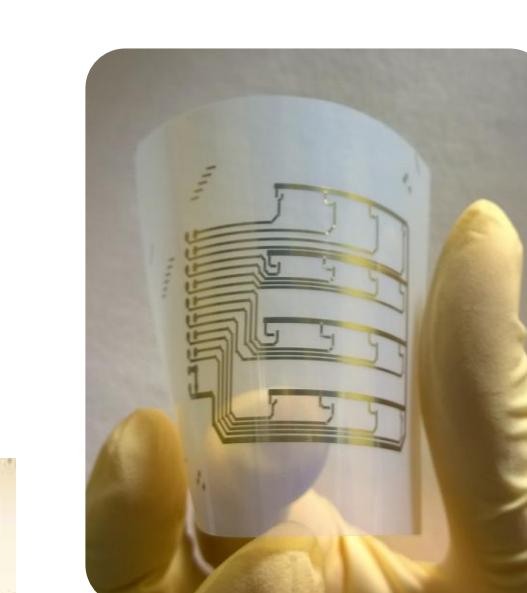
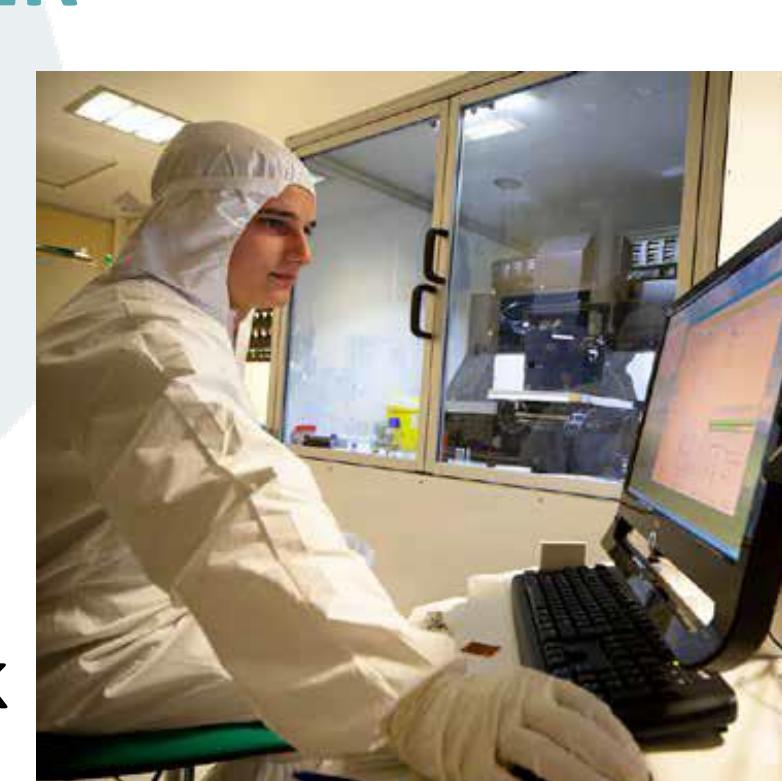
Mirror covered with Au



INKJET PRINTING

CERADROP X-SERIES INKJET PRINTER

- 2 Dimatix Printhead (128 Nozzles each, Ø35 µm)
- 1 Mono nozzle print-head Diameter of Nozzle 20, 30, or 35 µm
- 1 IR Dryer
- Printing with AgNPs ink and carbon ink



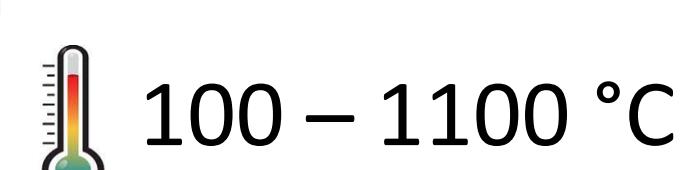
Ag circuit
printed on PET



RAPID WAFER HEATING SYSTEM

JIPELEC JETFIRST 200

Gas process : N₂ - N₂/5%H₂ - O₂ - Ar

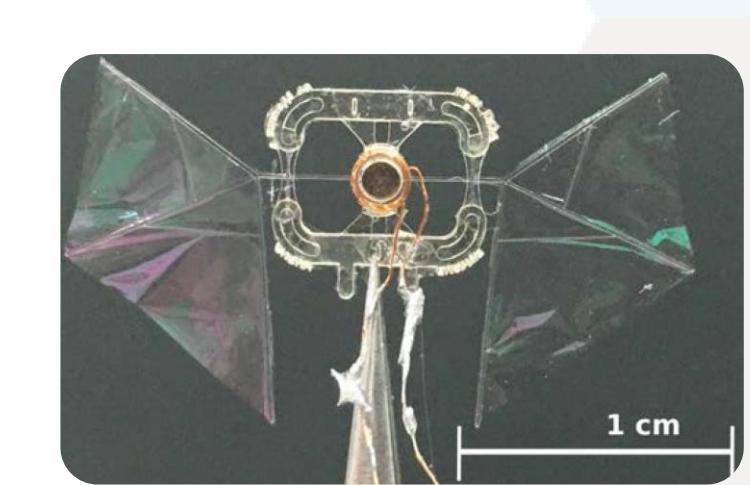
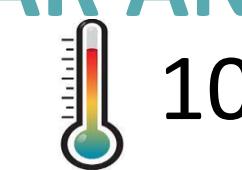


FURNACES

ATMOSPHERIC PRESSURE TUBULAR ANNEALING FURNACES

CARBOLITE

Gas process : N₂ - N₂/5%H₂



OVMi-Parylene

PARYLENE

COMELEC C20S

Room temperature deposition (3 steps):

- Vaporization of the solid dimer
- Pyrolysis of the dimer to yield the monomeric diradical
- Simultaneous adsorption and polymerization of the monomer on the substrate (at room temperature)

Thickness ranging from 30 nm to 50 µm

